

# Evaluation of Subsystem Clock Oscillation Circuit

[M38D59GFHP-80P] LQFP(12x12) 0.5mm pitch

Measurement conditions :3.3V, 5.0V

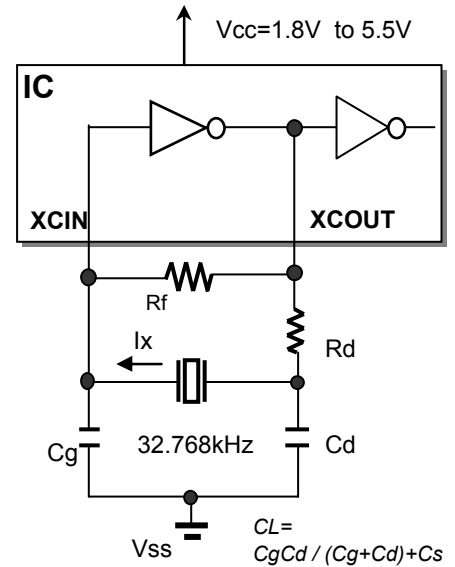
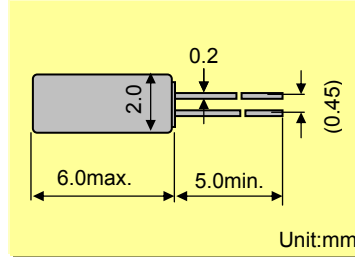


Model :VT-200  
 Frequency :Fo=32.768kHz  
 Frequency tolerance :dF/Fo= +/-20x10<sup>6</sup>  
 Load capacitance :CL=6.0pF  
 Equivalent series resistance :R1=50kohm max  
 Max. drive level :DL=1x10<sup>6</sup>W max  
 Level of drive :DL=0.1x10<sup>6</sup>W typ

### FEATURES

- 1.Compact tubular package
- 2.Photolithographic process
- 3.Excellent shock resistance and environmental characteristics.
- 4.Real time clocks, Timers, Portable applications

### DIMENSIONS(VT-200)



Remark) Ix : current through crystal

MODEL:VT-200 6.0pF with M38D59GFHP at 25°C

Key specifications	Vcc=3.3V	Vcc=5.0V	Remarks
Negative feedback resistance : Rf ( M ohm )	10	10	
Current control resistance : Rd ( k ohm )	330	330	Control drive level & secure phase margin
Capacitance at gate : Cg ( pF )	6	6	Optimal capacity in response to CL
Capacitance at drain : Cd ( pF )	5	5	( CL = Cd // Cg + stray capacitance )

Circuit characteristics ( at 25°C )	Vcc=3.3V	Vcc=5.0V	Remarks
Matching Accuracy : df / f ( x10 <sup>-6</sup> )	-1.1	2.6	Frequency offset volume at specified Vdd
Voltage Fluctuation : +/-df / V ( x10 <sup>-6</sup> )	0.9	0.9	Vdd +/-10% ( Standard operating voltage range )
Drive Level : DL ( x10 <sup>-6</sup> W )	0.02	0.02	DL=Ix <sup>2</sup> Re < 1x10 <sup>6</sup> W, Re=R1( 1 + Co / CL ) <sup>2</sup>
Negative resistance :   - RL   ( kohm )	598	598	5 times larger than R <sub>1MAX</sub>
Oscillation allowance : M ( times )	12.0	12.0	Judgemental standard of oscillation stability
Voltage of oscillation start : Vstart ( V )	1.66	1.66	
Voltage of oscillation stop : Vstop ( V )	1.43	1.43	
Oscillation start up time : Ts ( sec )	0.56	0.57	Time to reach 90% of output level

Temperature characteristics of circuit		Vcc=3.3V	Vcc=5.0V	Remarks
at -20°C	Variation : df / T ( x10 <sup>-6</sup> )	-60	-61	Typ.Tp=25°C ( K = -3.5x10 <sup>-8</sup> / °C <sup>2</sup> )
at +85°C	Variation : df / T ( x10 <sup>-6</sup> )	-139	-139	Typ.Tp=25°C ( K = -3.5x10 <sup>-8</sup> / °C <sup>2</sup> )

The above mentioned value is only for your reference. The value is for the arbitrary samples and does not guarantee the product's characteristics. Please review and check above parameters at customer's end.

### Seiko Instruments USA Inc.

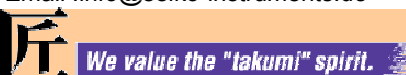
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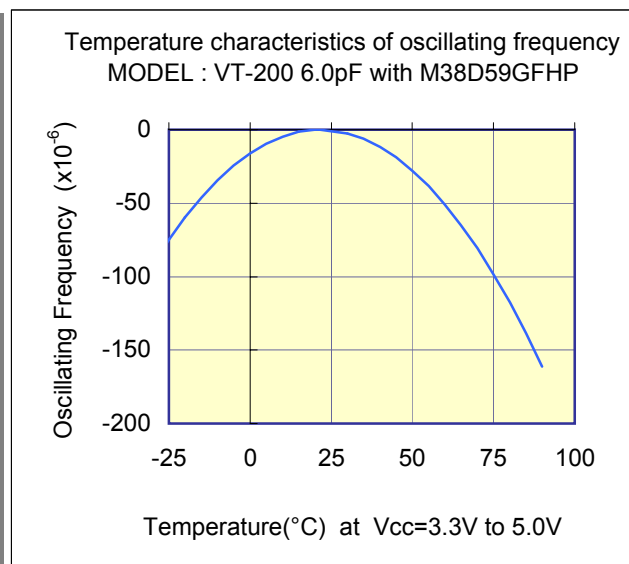
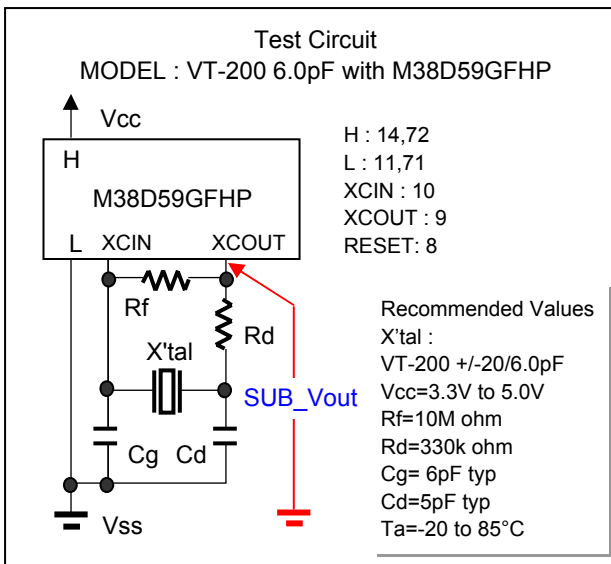
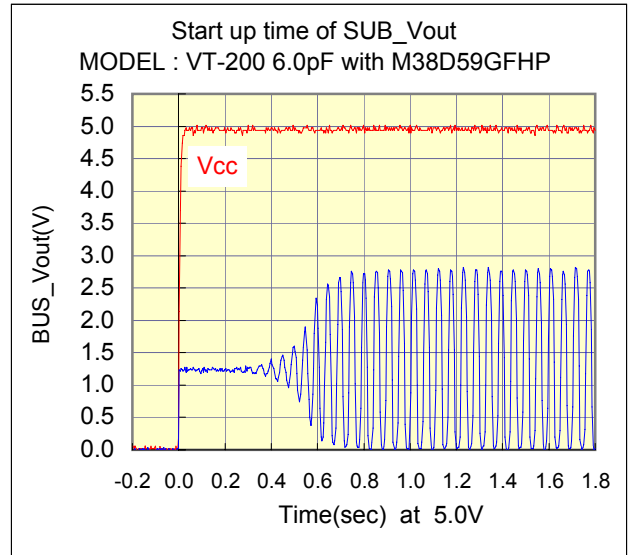
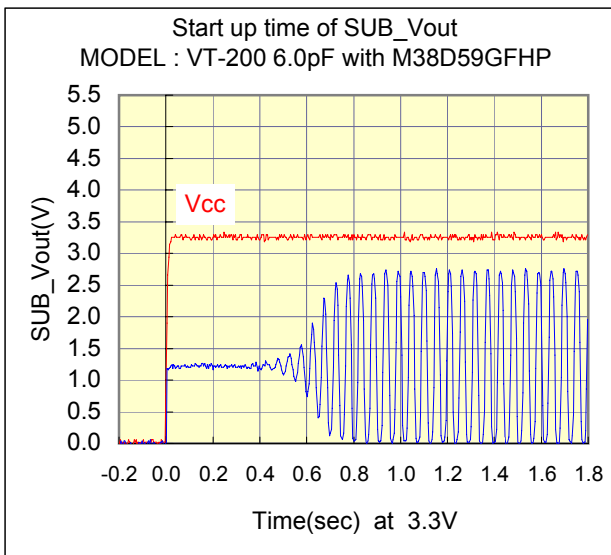
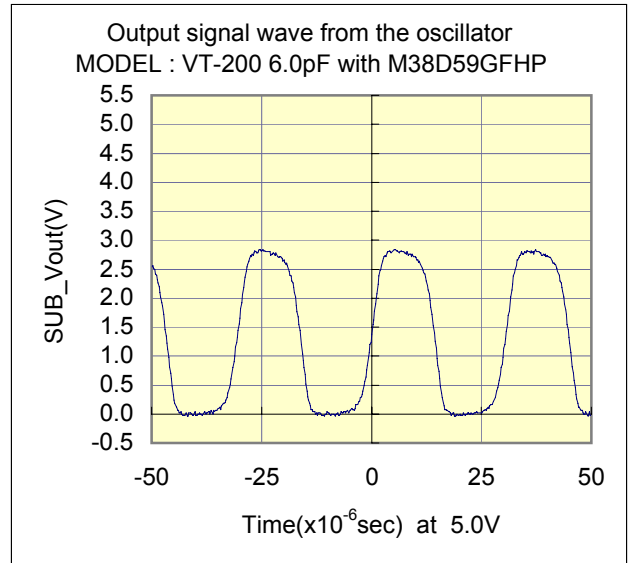
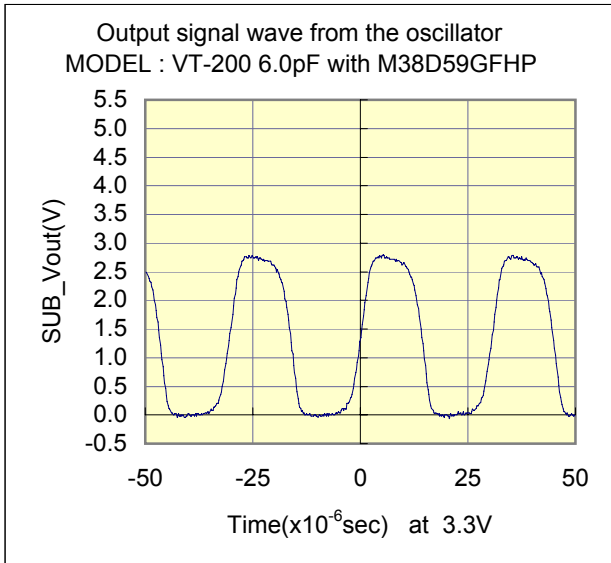


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## Test Data at 25°C



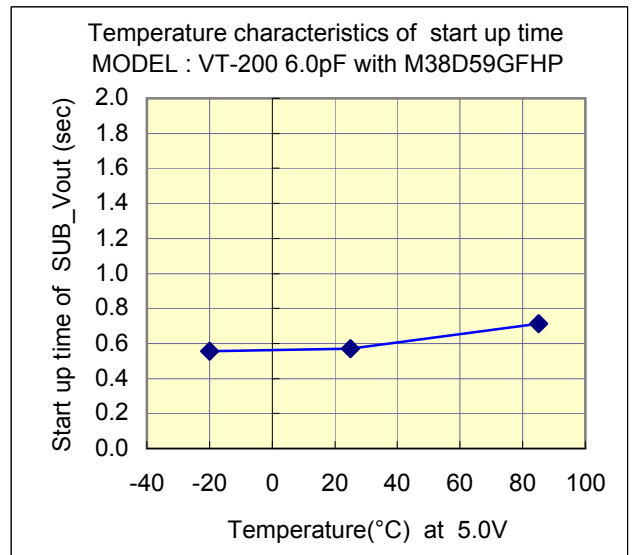
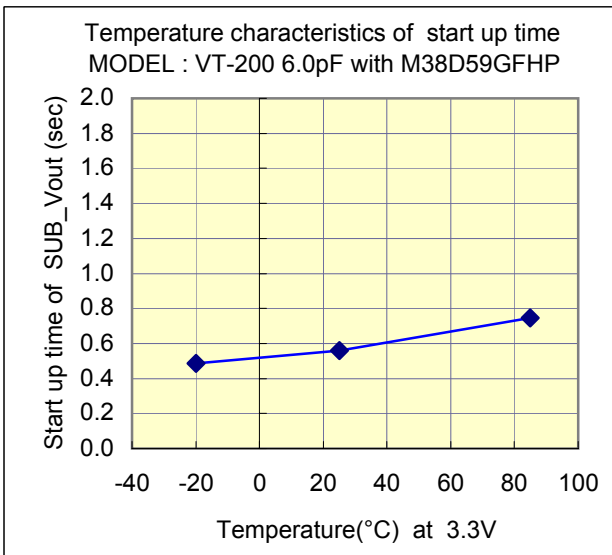
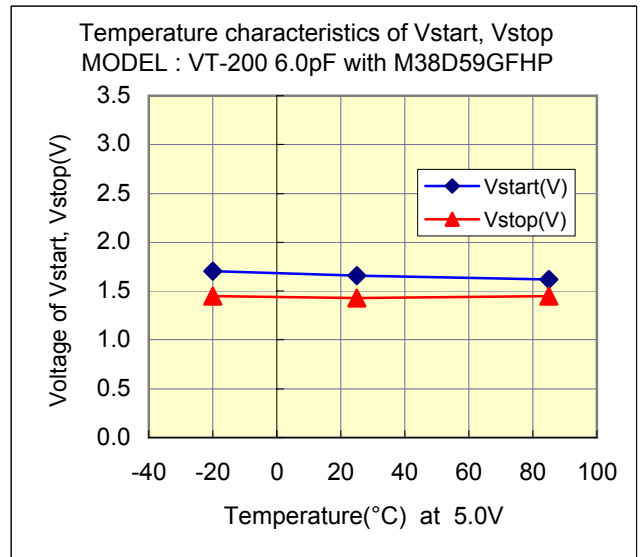
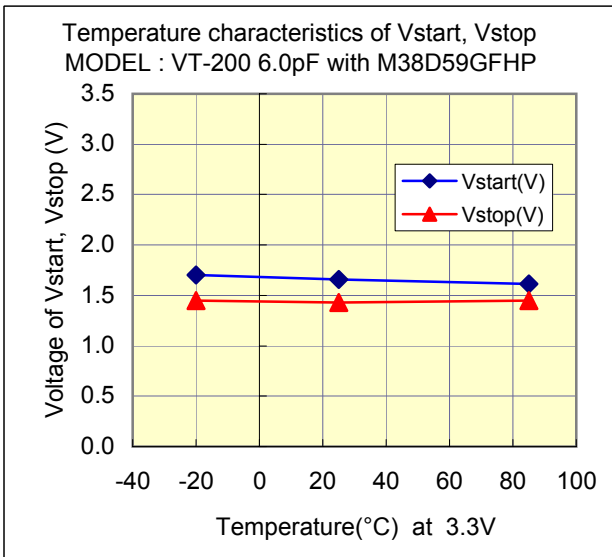
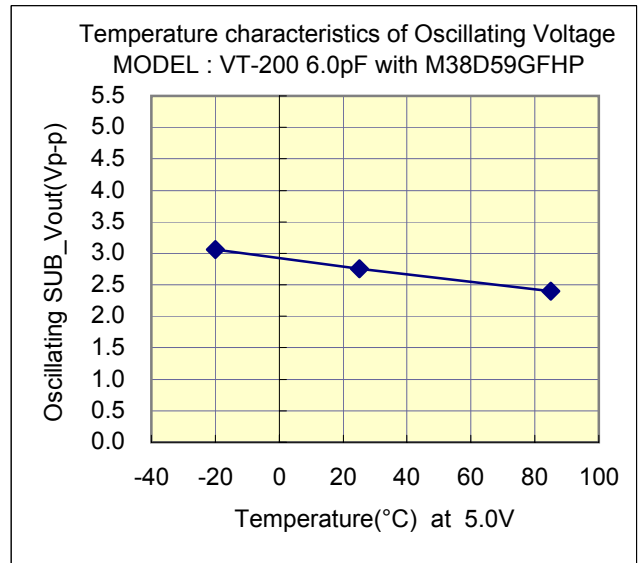
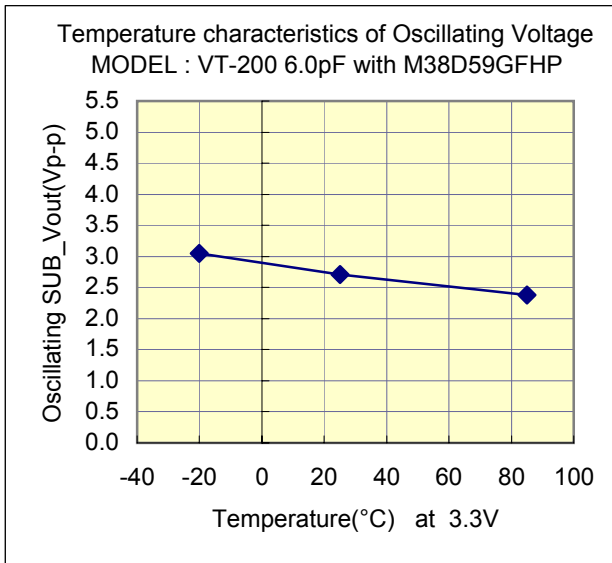
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## Test Data : Temperature characteristics



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## Referential components layout(see Figure 1)

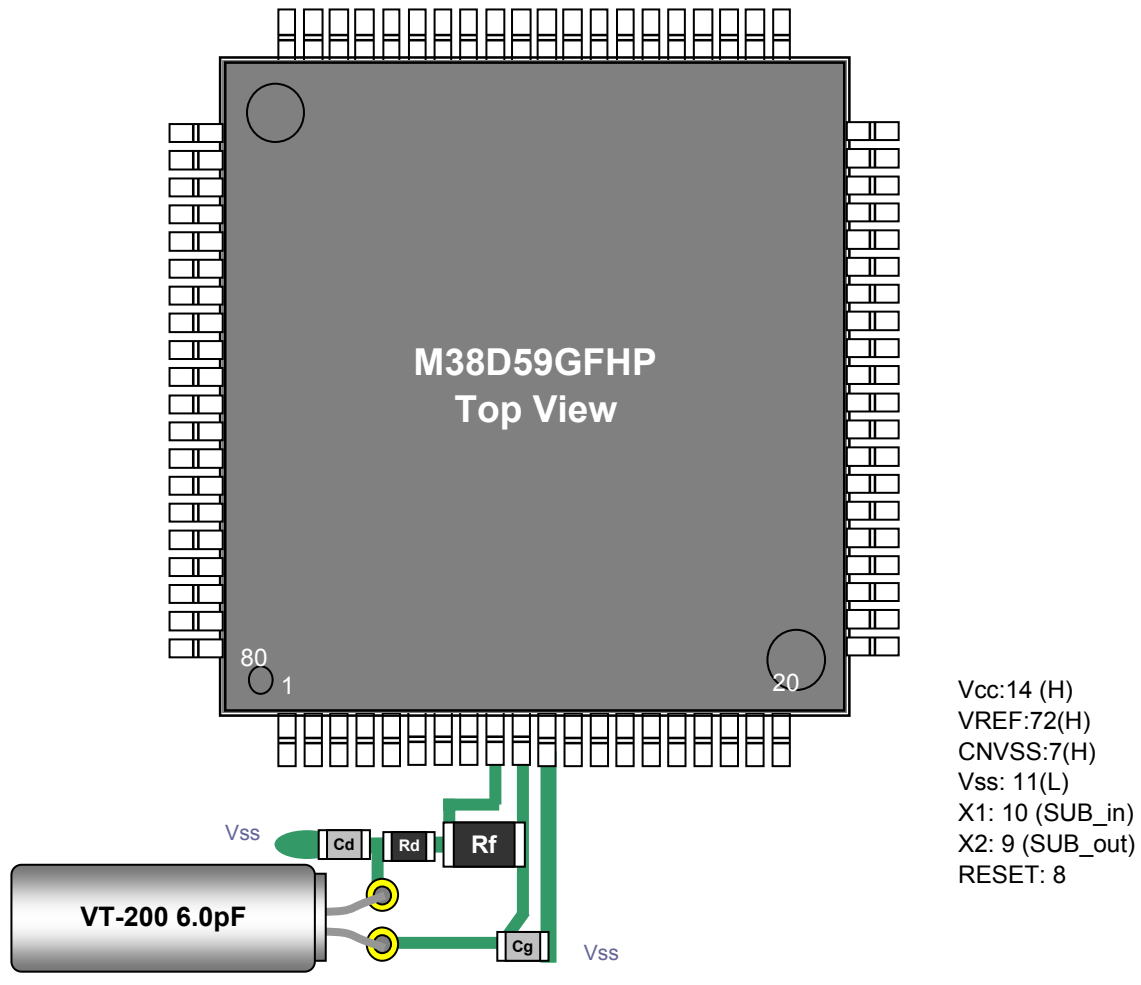


Figure 1 Referential components layout

## Notes for Board Design

When using a crystal resonator, place the resonator and its load capacitors as close as possible to SUB\_in and SUB\_out pins.

Other signal lines should be routed away from the resonator circuit to prevent induction from interfering with correct oscillation (see figure 2).

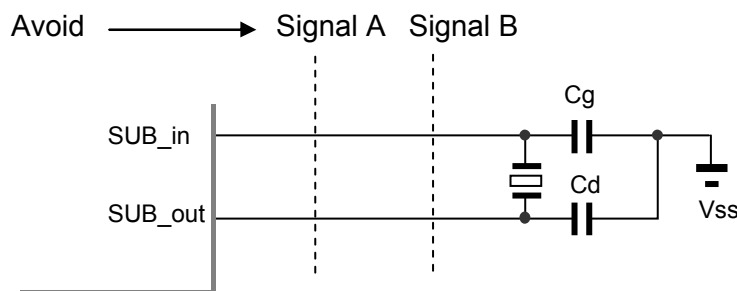


Figure 2 Example of Incorrect Board Design

**Remark** When using the subsystem clock, insert resistors Rd in series on the SUB\_out side.

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## [Evaluation Sample : VT-200 6.0pF at 25°C]

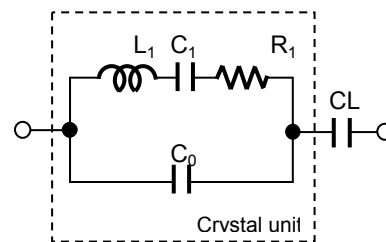
SAMPLE	No.	CL( pF )	Fo( Hz )	fr( Hz )	R1( kohm )	Co( pF )	C1( fF )	Q( k )
VT-200 6.0pF	1	6	32767.90	32762.79	28.8	0.88	2.148	78.6
	2	6	32768.18	32763.04	27.8	0.89	2.161	80.9
	3	6	32768.19	32763.00	27.2	0.90	2.187	81.7

## [IC Test Data : IC samples Rf=10M ohm,Rd=330k ohm,Cg=6pF,Cd=5pF at 25°C]

Vcc(V)	IC samples	Fosc( Hz )	df / f( x10 <sup>-6</sup> )	DL(x10 <sup>-6</sup> W)	-RL  ( kohm )	Vstart( V )	Ts(sec)
5.0	TYP	32767.990	2.59	0.02	598	1.66	0.57
	HH	32768.040	4.12	0.03	598	1.85	0.56
	HL	32767.950	1.37	0.02	598	1.72	0.58
	LH	32768.010	3.21	0.02	598	1.63	0.50
	LL	32767.920	0.46	0.02	598	1.49	0.56
3.3	TYP	32767.870	-1.07	0.02	598	1.66	0.56
	HH	32767.920	0.46	0.03	598	1.85	0.53
	HL	32767.819	-2.62	0.02	598	1.72	0.54
	LH	32767.900	-0.15	0.02	598	1.63	0.53
	LL	32767.800	-3.20	0.02	598	1.49	0.53

### Remark ( see figure 3 )

$$F_o = f_r \times \left\{ \frac{C_1}{2 \times (C_o + C_L)} + 1 \right\} \text{ ( Hz )}$$



Fo : Load resonance frequency  
fr : Resonance frequency  
R1 : Motional resistance  
C1 : Motional capacitance  
Co : Shunt capacitance  
CL : Load Capacitance

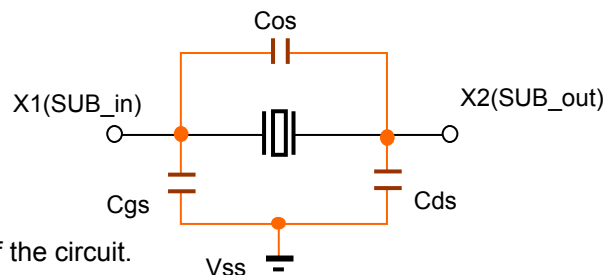
Figure 3 Equivalent circuit of crystal unit, and CL

### Remark ( see figure 4 )

Approximate formula of the load capacitance of the circuit CL.

$$CL = C_g \times C_d / (C_g + C_d) + C_s \text{ ( pF )}$$

Where Cs(=2 to 4pF) Stands for stray capacitance of the circuit.



Cos : X1\_X2 Stray capacitance  
Cgs : X1\_Vss Stray capacitance  
Cds : X2\_Vss Stray capacitance

Figure 4 Stray capacitance Cos,Cgs,Cds of the circuit

Resonator circuit constants will differ depending on the resonator element, stray capacitance in its interconnecting circuit, and other factors. Suitable constants should be determined in consultation with the resonator element manufacturer.